



PNP GENERAL PURPOSE SWITCHING TRANSISTOR

VOLTAGE 40 Volt POWER 225 mWatt

FEATURES

- PNP epitaxial silicon, planar design
- Collector-emitter voltage VCE = -40V
- Collector current IC = -200mA
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. . (Halogen Free)

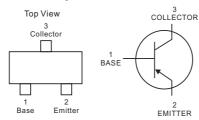
MECHANICAL DATA

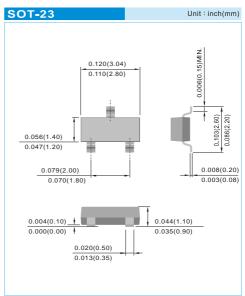
Case: SOT-23, Plastic

Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: S2A





ABSOLUTE RATINGS

Parameter	Symbol	Value	Units
Collector - Emitter Voltage	VCEO	-40	V
Collector - Base Voltage	Vсво	-40	V
Emitter - Base Voltage	VEBO	-5	V
Collector Current - Continuous	Ic	-200	mA

THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Units
Max Power Dissipation (Note 1)	Ртот	330	mW
Thermal Resistance , Junction to Ambient	Rеja	375	°C/W
Operating Junction Temperature and Storage Temperature Range	TJ,Tstg	-55 to 150	°C

Note 1: Transistor mounted on FR-5 board 1 x 0.75 x 0.062 in.



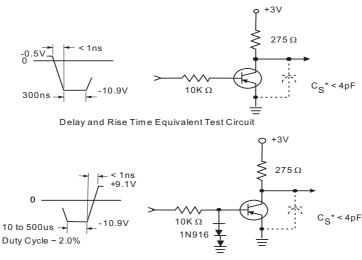


ELECTRICAL CHARACTERISTICS

	1				,	
Parameter	Symbol	Test Condition	MIN.	TYP.	MAX.	Units
Collector - Emitter Breakdown Voltage	V(BR)CEO	IC=-1mA, IB=0	-40	-	-	V
Collector - Base Breakdown Voltage	V(BR)CBO	IC=-10uA, IE=0	-40	-	-	٧
Emitter - Base Breakdown Voltage	V _(BR) EBO	IE=-10uA, IC=0	-5	-	-	V
Base Cutoff Current	Івь	VCE=-30V, VEB=-3V	-	-	-50	nA
Collector Cutoff Current	Icex	VCE=-30V, VEB=-3V	-	-	-50	nA
DC Current Gain (Note 2)	h _{FE}	IC=-0.1mA, VCE=-1V IC=-1mA, VCE=-1V IC=-10mA, VCE=-1V IC=-50mA, VCE=-1V IC=-100mA, VCE=-1V	60 80 100 60 30	- - - -	- 300 -	-
Collector - Emitter Saturation Voltage (Note 2)	VCE(SAT)	IC=-10mA, IB=-1mA IC=-50mA, IB=-5mA	-	-	-0.25 -0.4	V
Base - Emitter Saturation Voltage (Note 2)	VBE(SAT)	IC=-10mA, IB=-1mA IC=-50mA, IB=-5mA	-0.65 -		-0.85 -0.95	V
Collector - Base Capacitance	Ссво	VCB=-5V, IE=0, f=1MHz	-	-	4.5	pF
Emitter - Base Capacitance	Сево	VEB=-0.5V, IC=0, f=1MHz	-	-	10	pF
Delay Time	td	Vcc=-3V,VBE=-0.5V, lc=-10mA,IB=-1mA	-	-	35	ns
Rise Time	tr	Vcc=-3V,VBE=-0.5V, lc=-10mA,lB=-1mA	-	-	35	ns
Storage Time	ts	VCC=-3V,IC=-10mA IB1=IB2=-1mA	-	-	225	ns
Fall Time	tf	VCC=-3V,IC=-10mA IB1=IB2=-1mA	-	-	75	ns
Current Gain-Bandwidth Product	f _T	Ic=-10mA, Vc==-20V, f=100MHz	250	-	-	MHz

Note 2: Pulse Test: Pulse Width \leq 300 us, Duty Cycle \leq 2.0%.

SWITCHING TIME EQUIVALENT TEST CIRCUITS



Storage and Fall Time Equivalent Test Circuit





ELECTRICAL CHARACTERISTICS CURVE

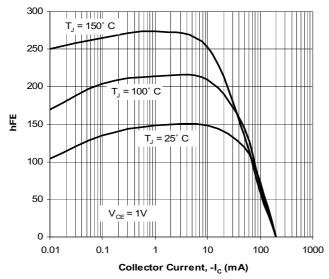


Fig. 1. Typical h_{FE} vs. Collector Current

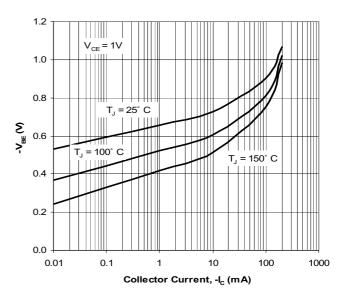


Fig. 2. Typical V_{BE} vs. Collector Current

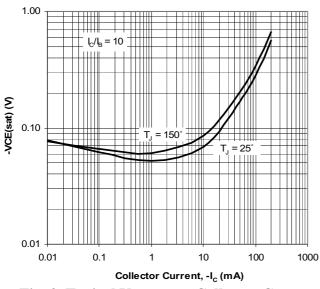


Fig. 3. Typical $V_{CE\,(sat)}$ vs. Collector Current

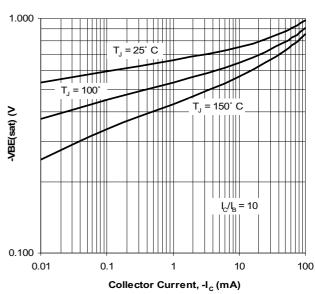


Fig. 4. Typical V_{BE (sat)} vs. Collector Current

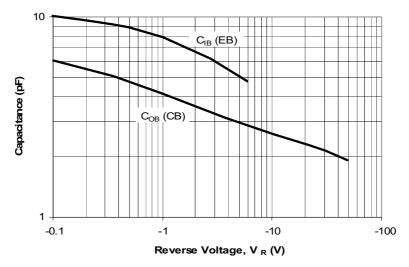
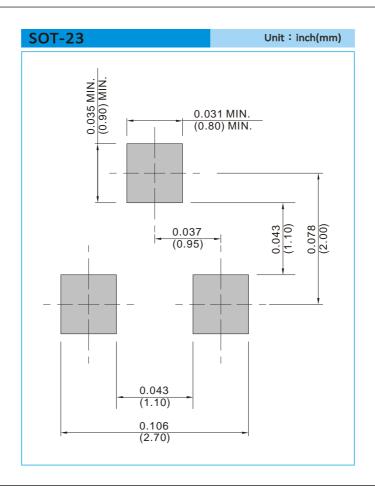


Fig. 5. Typical Capacitances vs. Reverse Voltage





MOUNTING PAD LAYOUT



ORDER INFORMATION

• Packing information

T/R - 12K per 13" plastic Reel

T/R - 3K per 7" plastic Reel

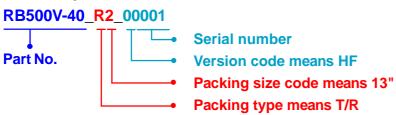




Part No_packing code_Version

MMBT3906_R1_00001 MMBT3906_R2_00001

For example:



Packing Code XX			Version Code XXXXX			
Packing type	1 st Code	Packing size code	2 nd Code	HF or RoHS	1 st Code	2 nd ~5 th Code
Tape and Ammunition Box (T/B)	Α	N/A	0	HF	0	serial number
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number
Bulk Packing (B/P)	В	13"	2			
Tube Packing (T/P)	Т	26mm	X			
Tape and Reel (Right Oriented) (TRR)	S	52mm	Y			
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U			
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D			





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